16-bit to 32-bit Demux PCI Hot-plug Bus Switch

HITACHI

ADE-205-673 (Z)

Preliminary Rev. 0 Feb. 2002

Description

The HD74CBT32160C device provides 16-bit to 32-bit demux PCI Hot-plug bus switching. The low on state resistance of the switch allows connections to be made with minimal propagation delay. Select control (SEL1, SEL2) inputs, select the appropriate B1 and B2 outputs for the A-input data.

Features

- Minimal propagation delay through the switch.
- 5 Ω switch connection between two ports.
 Pullup on B1 and B2 ports.
- TTL-compatible input levels.
- Ultra low quiescent power. -Ideally suited for notebook applications.
- Package type Product code example: HD74CBT32160CTEL

Package type	Package code	Package suffix	Taping code
TSSOP-56pin	TTP-56DAV	Т	EL (1,000 pcs / Reel)

Function Table

Inputs

SEL1	SEL2	Function
L	Н	nA to nB1
Н	L	nA to nB2
L	L	nA to nB1 and nB2
Н	Н	nB1, nB2 = VBIAS

H: High level

L: Low level



Pin Arrangement

1B1 1	5	6 1A
2B1 2	5	5 1B2
2A 3	5	4 2B2
3B1 4	5	3 3A
4B1 5	5	2 3B2
4A 6	5	1 4B2
5B1 7	5	0 5A
6B1 8	4	9 5B2
6A 9	4	8 6B2
7B1 10		7 7A
8B1 11		6 7B2
8A 12		5 8B2
GND 13		4 GND
Vcc 14		3 Vcc
9B1 15		2 9A
10B1 16		1_9B2
10A 17		0 10B2
11B1 <u>18</u>		9 11A
12B1 <u>19</u>		8 11B2
12A 20		7 12B2
13B1 21		6 13A
14B1 22		5 13B2
14A 23		4 14B2
15B1 24		3 15A
16B1 25		2 15B2
16A 26		1 16B2
VBIAS1 27		O VBIAS2
SEL1 28	2	9 SEL2
	(Top view)	

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V _{cc}	-0.5 to 7.0	V	
Input voltage range ¹	V	-0.5 to 7.0	V	
Input clamp current	I _{IK}	-50	mA	V ₁ < 0
Continuous output current	I _o	128	mA	$V_{o} = 0$ to V_{cc}
Continuous current through V_{cc} or GND	$I_{\rm cc}$ or $I_{\rm gnd}$	±100	mA	
Maximum power dissipation at Ta = 25° C (in still air) ²	P _T	1.32	W	
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

1. The input and output voltage ratings may be exceeded even if the input and output clamp-current ratings are observed.

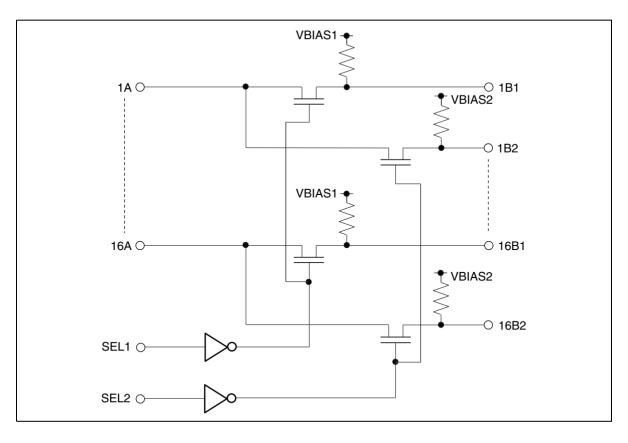
2. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{cc}	4.5	5.5	V	
	VBIAS	1.3	V _{cc}		
Input voltage range	V	0	5.5	V	
Output voltage range	V _{I/O}	0	5.5	V	
Input transition rise or fall rate	$\Delta t / \Delta v$	0	5	ns / V	$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Logic Diagram



DC Electrical Characteristics

 $(Ta = -40 \text{ to } 85^{\circ}C)$

Item	Symbol	V _{cc} (V)	Min	Тур⁺	Max	Unit	Test conditions
Clamp diode voltage	V _{IK}	4.5	_	—	-1.2	V	I _{IN} = -18 mA
Input voltage	V _{IH}	4.0 to 5.5	2.0	_	_	V	
	V	4.0 to 5.5		_	0.8		
On-state switch resistance ^{*2}	R _{on}	4.5	_	5	8	Ω	$V_{IN} = 0 V,$ $I_{IN} = 48 \text{ mA}$
		4.5	_	10	15	_	V _{IN} = 2.4 V, I _{IN} = 15 mA
Input current	I _{IN}	0 to 5.5		_	±1.0	μA	$V_{IN} = 5.5 \text{ V or GND}$
Off-state leakage current	I _{oza}	5.5	_	—	20	μA	A = 5.5 V, $V_{_{BIAS}}$ = 5.5 V
Current			-1.0	—	—		A = 0 V, V_{BIAS} = 5.5 V
	I _{ozb}	_	_	_	±1.0	_	$B = 5.5 \text{ V}, \text{ V}_{_{BIAS}} = 5.5 \text{ V}$
			-5	_	-0.25	mA	$B=0~V,~V_{_{\text{BIAS}}}=5.5~V$
Quiescent supply current	I _{cc}	5.5	_	—	3	μA	$V_{IN} = V_{cc}$ or GND, $I_{o} = 0 \text{ mA}$
Increase in I _{cc} per input ^{'3}	ΔI_{cc}	5.5	—	_	2.5	mA	One input at 3.4 V, other inputs at V_{cc} or GND

Notes: For condition shown as Min or Max use the appropriate values under recommended operating conditions.

1. All typical values are at $V_{cc} = 5 V$ (unless otherwise noted), Ta = 25°C.

2. Measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lower voltage of the two (A or B) terminals.

3. This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{cc} or GND.

Capacitance

 $(Ta = 25^{\circ}C)$

Item		Symbol	V _{cc} (V)	Min	Тур	Max	Unit	Test conditions
Control input capacitance		C _{IN}	5.0	—	5	—	pF	$V_{IN} = 0 \text{ or } 3 \text{ V}$
Input / output	A port	$\boldsymbol{C}_{\text{I/O (OFF)}}$	5.0	_	10	_	pF	$V_{o} = 0 \text{ or } 3 \text{ V}$
capacitance	B port	_		_	7	_		SEL1, SEL2 = V_{cc}

Note: This parameter is determined by device characterization is not production tested.

Switching Characteristics

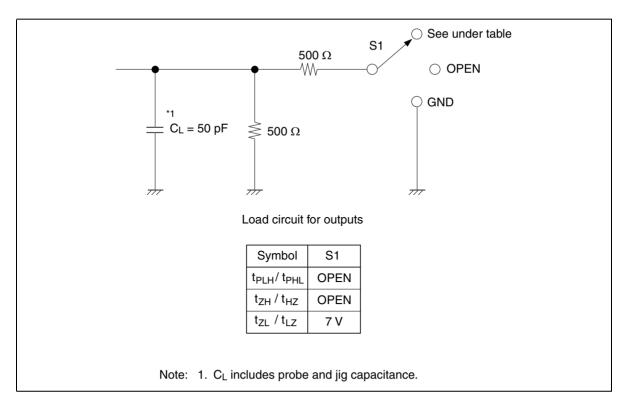
 $(Ta = -40 \text{ to } 85^{\circ}\text{C})$

• $V_{cc} = 5.0 \pm 0.5 \text{ V}, V_{BIAS} = V_{cc}$

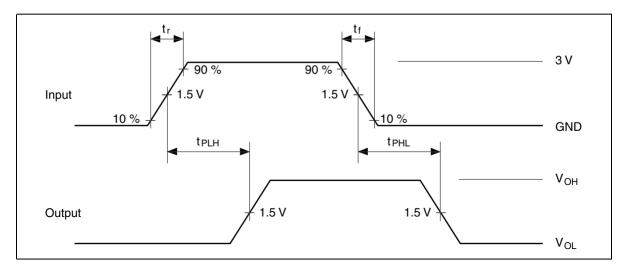
Item	Symbol	Min	Max	Unit	Test conditions	FROM (Input)	TO (Output)
Propagation delay time ^{*1}	t _{plh} t _{phl}	—	0.25	ns	$C_L = 50 \text{ pF}$ $R_L = 500 \Omega$	A or B	B or A
Enable time	t _{zH} t _{zL}	2.0	7.0	ns	$C_L = 50 \text{ pF}$ $R_L = 500 \Omega$	SEL	A or B
Disable time	t _{HZ}	2.0	6.0	ns	$C_{L} = 50 \text{ pF}$	SEL	A or B
	t _{LZ}	2.0	7.0		$R_{L} = 500 \Omega$		

Notes: 1. The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

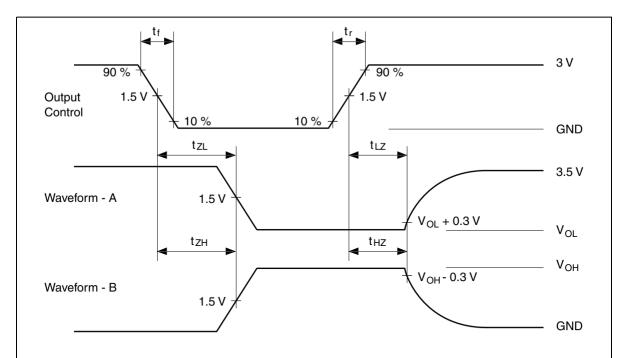
Test Circuit



Waveforms - 1

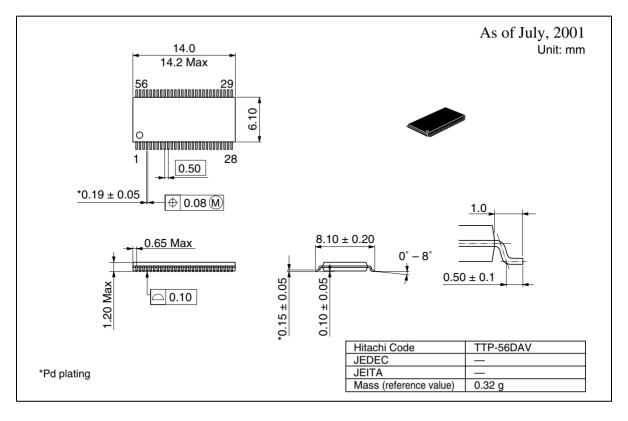


Waveforms – 2



- Notes: 1. All input pulses are supplied by generators having the following characteristics : $PRR \le 10 \text{ MHz}, Z_0 = 50 \Omega, t_f \le 2.5 \text{ ns}, t_f \le 2.5 \text{ ns}.$
 - 2. Waveform A is for an output with internal conditions such that the output is low except when disabled by the output control.
 - 3. Waveform B is for an output with internal conditions such that the output is high except when disabled by the output control.
 - 4. The output are measured one at a time with one transition per measurement.

Package Dimensions



Disclaimer

- 1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
- 2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
- 3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
- 4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as fail-safes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
- 5. This product is not designed to be radiation resistant.
- 6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
- 7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

Sales Offices

HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: (03) 3270-2111 Fax: (03) 3270-5109

URL http://www.hitachisemiconductor.com/

For further information write to:

(America) Inc. 179 East Tasman Drive San Jose, CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223	Hitachi Europe Ltd. Electronic Components Group Whitebrook Park Lower Cookham Road Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 585200 Hitachi Europe GmbH Electronic Components Group Dornacher Straße 3 D-85622 Feldkirchen Postfach 201, D-85619 Feldkirchen Germany Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00	Hitachi Asia Ltd. Hitachi Tower 16 Collyer Quay #20-00 Singapore 049318 Tel : <65>-538-6533/538-8577 Fax : <65>-538-6933/538-3877 URL : http://semiconductor.hitachi.com.sg Hitachi Asia Ltd. (Taipei Branch Office) 4/F, No. 167, Tun Hwa North Road Hung-Kuo Building Taipei (105), Taiwan Tel : <886>-(2)-2718-3666 Fax : <886>-(2)-2718-3666 Fax : <28222 HAS-TP URL : http://www.hitachi.com.tw	Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower World Finance Centre, Harbour City, Canton Road Tsim Sha Tsui, Kowloon Hong Kong Tei : <852>-(2)-735-9218 Fax : <852>-(2)-730-0281 URL : http://semiconductor.hitachi.com.hk
		•	2. All rights reserved. Printed in Japan.

Colophon 5.0